Electronic Patent Application Fee Transmittal								
Application Number:	10	10814482						
Filing Date:	31	31-Mar-2004						
Title of Invention:	M/str	Method for fabricating strained silicon-on-insulator structures and strained silicon-on insulator structures formed thereby						
First Named Inventor/Applicant Name:	Тс	Toshiharu Furukawa						
Filer:	w	William R. Allen/Angela Malik						
Attorney Docket Number:	R	ROC920030399US1						
Filed as Large Entity								
Utility Filing Fees								
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)			
Basic Filing:			1		1			
Pages:								
Claims:								
Miscellaneous-Filing:								
Petition:								
Patent-Appeals-and-Interference:					Y			
Filing a brief in support of an appeal		1402	1	500	500			
Post-Allowance-and-Post-Issuance:			· · · · · · · · · · · · · · · · · · ·					
Extension-of-Time								

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
	Total in USD (\$) 5			500